

## 1015 MP

15 Watt, 50 Volts, Class C Avionics 1025 - 1150 MHz

#### **GENERAL DESCRIPTION**

The 1015 MP is a COMMON BASE bipolar transistor. It is designed for pulsed systems in the frequency band 1025-1150 MHz. The device has gold thin-film metallization for proven highest MTTF. The transistor includes input prematch for broadband capability. Low thermal resistance package reduces junction temperature, extends life.

#### ABSOLUTE MAXIMUM RATINGS

Maximum Power Dissipation @ 25°C<sup>2</sup> 50 Watts Pk

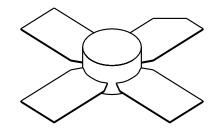
**Maximum Voltage and Current** 

BVcesCollector to Emitter Voltage65 VoltsBVeboEmitter to Base Voltage3.5 VoltsIcCollector Current1.0 Amps Pk

**Maximum Temperatures** 

Storage Temperature  $-65 \text{ to} + 150^{\circ}\text{C}$ Operating Junction Temperature  $+200^{\circ}\text{C}$ 

# CASE OUTLINE 55FU, STYLE 1



### ELECTRICAL CHARACTERISTICS @ 25 °C

| SYMBOL              | CHARACTERISTICS   | TEST CONDITIONS   | MIN      | TYP      | MAX         | UNITS                     |
|---------------------|---|---|----------|----------|-------------|---------------------------|
| Pout Pin Pg ηc VSWR | Power Out Power Input Power Gain Efficiency Load Mismatch Tolerance | F= 1025-1150 MHz<br>Vcc = 50 Volts<br>PW = 10 μsec<br>DF = 1%<br>F = 1090 MHz | 15<br>10 | 11<br>40 | 1.5<br>20:1 | Watts<br>Watts<br>dB<br>% |

| BVebo<br>BVces<br>Hfe | Emitter to Base Breakdown Collector to Emitter Breakdown DC Current Gain to Emitter | Ie = 5 mA<br>Ic = 15mA                                   | 3.5<br>65<br>20 |     |            | Volts<br>Volts |
|-----------------------|---|--|-----------------|-----|------------|----------------|
| Cob<br>θjc²           | Output Capacitance Thermal Resistance   | Vce = 5V, Ic = 100 mA<br>Vcb = 50 V, f = 1 MHz<br>Pulsed | 20              | 5.0 | 7.5<br>3.5 | pF<br>°C/W     |

Note 1: At rated output power and pulse conditions

2: At rated pulse conditions

Initial Issue June, 1995

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